NSN 5961-01-498-9396

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-498-9396 **Inclosure Material:** Metal **Overall Length:** Between 0.200 inches and 0.225 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 working peak reverse voltage **Current Rating Per Characteristic:** 80.00 amperes forward current, average pascal **Special Features:** Surface mounted (square end cap) **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 case **Specification Data:** 81349-mil-s-19500/411 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No